Thyristor Semiconductor Device - Page 1 of 1



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Inclosure	Material:
Metal	

**Overall Length:** 

0.400 inches

- Mounting Facility Quantity:
- 1
- Internal Configuration:

Junction contact

**Mounting Method:** 

Threaded stud

**Features Provided:** 

Hermetically sealed case and mounting hardware

#### **Overall Width Across Flats:**

Between 0.424 inches and 0.437 inches

**Thread Size:** 

0.190 inches

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

400.0 forward voltage, peak

## **Current Rating Per Characteristic:**

2.00 amperes source cutoff current preset and 2.00 amperes source cutoff current minor

# Power Rating Per Characteristic:

20.0 watts small-signal input power, common-collector blank

### Maximum Operating Tempurature Per Measurement Point:

105.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: pnpn

### **Thread Series Designator:**

Unf

### **Terminal Type And Quantity:**

2 solder stud and 1 threaded stud

Shelf Life:

N/a

### Unit Of Measure:

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Demilitarization:

No

Fiig:

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